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Notice of Allowability	Application No.	Applicant(s)	3
	10/665,998	SCHAADT ET AL.	
	Examiner	Art Unit	
	Eric B. Chen	1765	
The MAILING DATE of this communication ap All claims being allowable, PROSECUTION ON THE MERITS herewith (or previously mailed), a Notice of Allowance (PTOL-8 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT of the Office or upon petition by the applicant. See 37 CFR 1.3	IS (OR REMAINS) CLOSED in 35) or other appropriate community RIGHTS. This application is	n this application. If not included unication will be mailed in due course.	. THIS
1. A This communication is responsive to 3/11/05.			
2. $igtimes$ The allowed claim(s) is/are <u>1-91 and 98-106</u> .			
3. $igotimes$ The drawings filed on <u>9/17/03</u> are accepted by the Exan	niner.		
4. Acknowledgment is made of a claim for foreign priority a) All b) Some* c) None of the: 1. Certified copies of the priority documents hat 2. Certified copies of the priority documents hat 3. Copies of the certified copies of the priority International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DAT noted below. Failure to timely comply will result in ABANDOI THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. A SUBSTITUTE OATH OR DECLARATION must be sull INFORMAL PATENT APPLICATION (PTO-152) which go the complete of the priority document sheets. The priority document sheets in the priority document sheets. The priority document sheets in the priority document sheets. The priority documents have sufficient to time the priority documents have sufficient to the priority documents have sufficien	eve been received. ave been received in Application documents have been received. E" of this communication to file NMENT of this application. bmitted. Note the attached EX gives reason(s) why the oath of the submitted. erson's Patent Drawing Reviewer's Amendment / Comment of the the header according to 37 Cliposit of BIOLOGICAL MAT	on No d in this national stage application from a reply complying with the requirement AMINER'S AMENDMENT or NOTICE r declaration is deficient. W (PTO-948) attached r in the Office action of the drawings in the front (not the back) of R 1.121(d). ERIAL must be submitted. Note the	ents : OF
Attachment(s) 1. ☐ Notice of References Cited (PTO-892)	5. ☐ Notice of Ir	formal Patent Application (PTO-152)	
2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948	B) 6. ☑ Interview S	ummary (PTO-413),	
3. ⊠ Information Disclosure Statements (PTO-1449 or PTO/SI		/Mail Date Amendment/Comment	
Paper No./Mail Date <u>4/4/05</u> 4. Examiner's Comment Regarding Requirement for Deposi	it 8 🕅 Evaminar's	Statement of Reasons for Allowance	
of Biological Material	9. 🔲 Other		
		NADINE G. NORTON	

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EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

- 2. Authorization for this examiner's amendment was given in a telephone interview with Gregory R. Muir on May 9, 2005.
- 3. The application has been amended as follows: claims 92-97 are cancelled.

Allowable Subject Matter

- 4. Claims 1-92 and 98-106 are allowed.
- 5. The following is an examiner's statement of reasons for allowance for claims 1 and 98: the prior art fails to teach or suggest pumping a portion of the gas out from the etching chamber, wherein the gas comprises a portion of the echant recipe and a portion of the etching product; and wherein another portion of the first amount of the etchant recipe is circulated in a circulation loop that passes through the etching chamber during the steps of pumping and providing the second discrete amount of the etchant recipe. The closest prior art, Tai, discloses: loading a microstructure (column 6, lines 59-60) into an etch chamber (110) (column 6, line 29), wherein the microstructure comprises a sacrificial material (column 6, lines 64-67) and one or more structural materials (column 6, line 29); providing a first discrete amount of spontaneous

vapor phase etchant recipe (column 5, lines 42-45) during a first feeding cycle of a sequence of feeding cycles for removing the sacrificial material (column 5, lines 56-67; column 6, lines 1-5; Figure 1B); pumping a portion of the gas from the etching chamber (column 5, lines 51-53); providing a second discrete amount of spontaneous vapor phase etchant recipe after the first feeding cycle and during a second feeding cycle that follows the first feeding cycle of the sequence of feeding cycles for removing the sacrificial materials (column 6, lines 4-5; column 7, lines 11-14; Figure 5). However, there is no motivation or suggestion of pumping a portion of the gas out from the etching chamber, wherein the gas comprises a portion of the echant recipe and a portion of the etching product; and wherein another portion of the first amount of the etchant recipe is circulated in a circulation loop that passes through the etching chamber during the steps of pumping and providing the second discrete amount of the etchant recipe, as in the context of claims 1 and 98.

The following is an examiner's statement of reasons for allowance for claim 45: the prior art fails to teach or suggest circulating the etchant and the diluent gas through a circulation loop that passes through the etch chamber. The closest prior art, Tai, discloses: (a) establishing a first pressure inside a first chamber (120) (column 4, lines 24-27), wherein the first pressure is equal to or lower than a pressure in a second chamber that contains a spontaneous vapor phase etchant (BrF₃ source, Figure 1A); (b) filling the first chamber (120) with an etchant (column 5, lines 42-45); (c) filling the first chamber (120) with a diluent gas such that the pressure inside the first chamber reaches a second pressure that is higher than the first pressure (column 4, lines 50-52);

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(d) circulating the etchant and the diluent gas through the etch chamber (column 5, lines 48-55). However, there is no motivation or suggestion of circulating the etchant and the diluent gas through a circulation loop that passes through the etch chamber, as in the context of claim 45.

- The following is an examiner's statement of reasons for allowance for claim 72: the prior art fails to teach or suggest circulating a first amount of spontaneous vapor phase etchant recipe via a first loop that passes through the etch chamber for removing the sacrificial material, as in the context of claim 72. The closest prior art, Tai, discloses: loading a microstructure (column 6, lines 59-60) into an etch chamber (110) (column 6, line 29), wherein the microstructure comprises a sacrificial material (column 6, lines 64-67) and one or more structural materials (column 6, line 29). However, there is no motivation or suggestion of circulating a first amount of spontaneous vapor phase etchant recipe via a first loop that passes through the etch chamber for removing the sacrificial material, as in the context of claim 72.
- 8. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Response to Arguments

9. In view of Applicants' Amendment to the Claims (pages 6 and 21), filed Mar. 11, 2005, the objection to claims 27 and 58 has been withdrawn.

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10. Applicant's arguments (Applicants' Remarks, page 17), filed Mar. 11, 2005, with respect to the rejection of claim 1 under 35 U.S.C. 102(b) as being anticipated by Tai have been fully considered and are persuasive, as discussed above. The rejection of claims 1-44 has been withdrawn.

11. Applicant's arguments (Applicants' Remarks, page 17), filed Mar. 11, 2005, with respect to the rejection of claim 45 under 35 U.S.C. 102(b) as being anticipated by Tai have been fully considered and are persuasive, as discussed above. The rejection of claims 45-71 has been withdrawn.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Eric B. Chen whose telephone number is (571) 272-2947. The examiner can normally be reached on Monday through Friday, 8AM to 4:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine G. Norton can be reached on (571) 272-1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

EBC

May 9, 2005

SUPERVISORY PATENT EXAMINER